

POWER SCHOTTKY RECTIFIER
MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	3 A
V_{RRM}	60 V
T_j (max)	150°C
V_F (max)	0.61 V

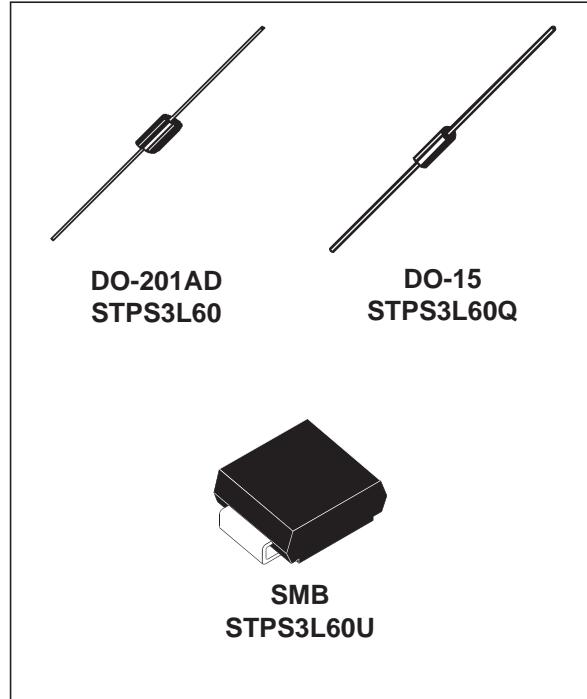
FEATURES AND BENEFITS

- NEGLIGIBLE SWITCHING LOSSES
- LOW THERMAL RESISTANCE
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Axial and Surface Mount Power Schottky rectifier suited for Switch Mode Power Supplies and high frequency DC to DC converters. Packaged in DO-201AD, DO-15 and SMB, this device is intended for use in low voltage, high frequency inverters and small battery chargers.

For applications where there are space constraints, e.g Telecom battery charger.


ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		60	V
$I_{F(RMS)}$	RMS forward current		10	A
$I_{F(AV)}$	Average forward current		3	A
	$T_L = 105^\circ\text{C} \ \delta = 0.5$ (DO-201AD, SMB)			
I_{FSM}	Surge non repetitive forward current		100	A
	$t_p = 10 \text{ ms Sinusoidal}$			
P_{ARM}	Repetitive peak avalanche power	$t_p = 1\mu\text{s} \ T_j = 25^\circ\text{C}$	2000	W
T_{stg}	Storage temperature range		- 65 to + 150	°C
T_j	Maximum operating junction temperature *		150	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/μs

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j - a)}$ thermal runaway condition for a diode on its own heatsink

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THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
$R_{th(j-l)}$	Junction to leads	Lead length = 10 mm	DO-201AD	20	°C/W
			SMB	20	
			DO-15	35	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I_R^*	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			150	μA
		$T_j = 100^\circ\text{C}$			4	15	mA
		$T_j = 125^\circ\text{C}$			14	30	
V_F^*	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 3 \text{ A}$			0.62	V
		$T_j = 100^\circ\text{C}$			0.53	0.61	
		$T_j = 125^\circ\text{C}$			0.51	0.59	
		$T_j = 25^\circ\text{C}$	$I_F = 6 \text{ A}$			0.79	
		$T_j = 100^\circ\text{C}$			0.62	0.71	
		$T_j = 125^\circ\text{C}$			0.6	0.69	

Pulse test : * $t_p = 380 \mu\text{s}$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation:
 $P = 0.44 \times I_{F(AV)} + 0.05 \times I_F^2(\text{RMS})$

Fig. 1: Average forward power dissipation versus average forward current.

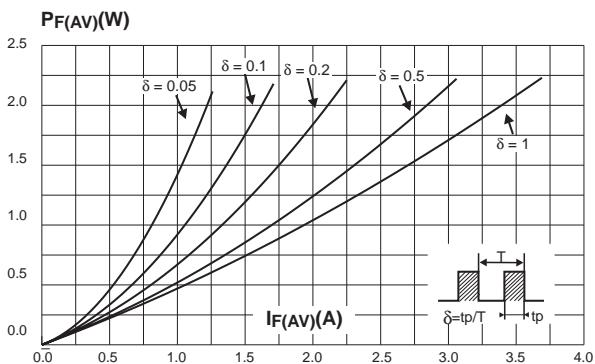


Fig. 2-1: Average forward current versus ambient temperature ($\delta = 0.5$) (DO-201AD, SMB).

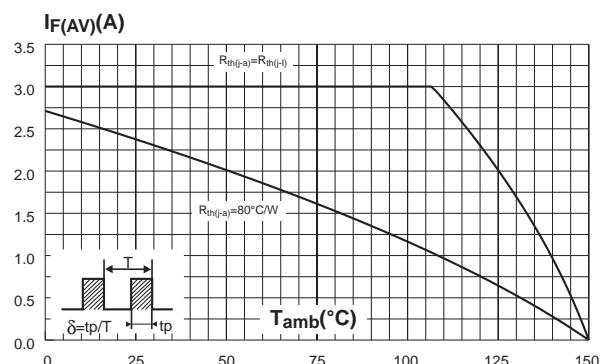


Fig. 2-2: Average forward current versus ambient temperature ($\delta = 0.5$) (DO-15).

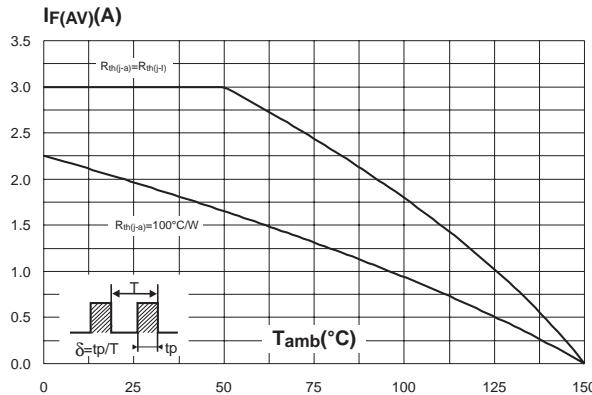


Fig. 4: Normalized avalanche power derating versus junction temperature.

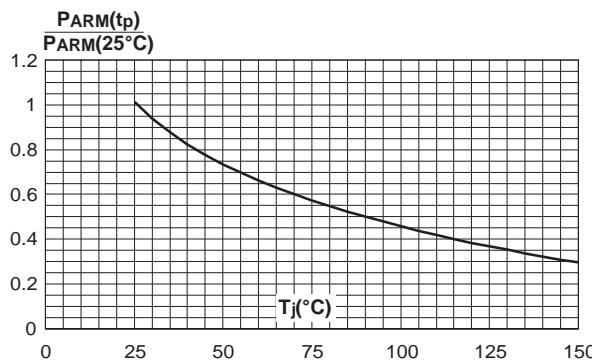


Fig. 5-2: Non repetitive surge peak forward current versus overload duration (maximum values) (DO-15).

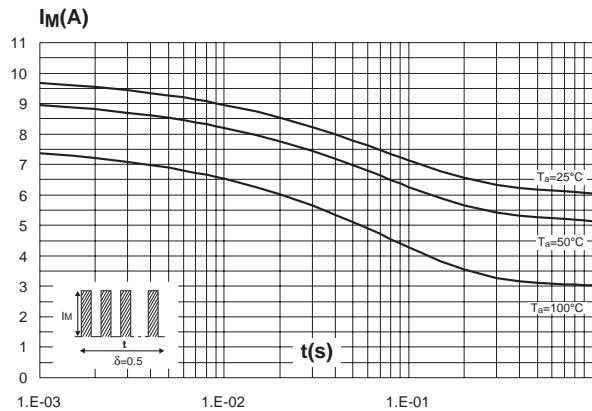


Fig. 3: Normalized avalanche power derating versus pulse duration.

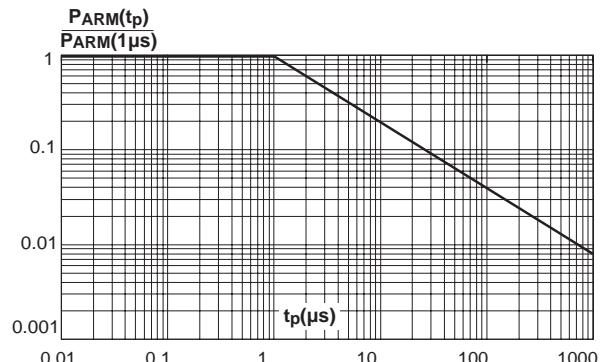


Fig. 5-1: Non repetitive surge peak forward current versus overload duration (maximum values) (DO-201AD, SMB).

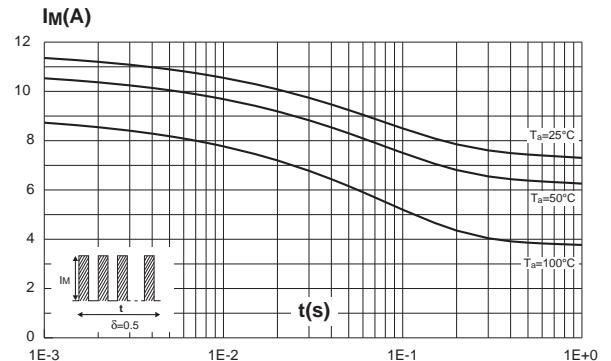
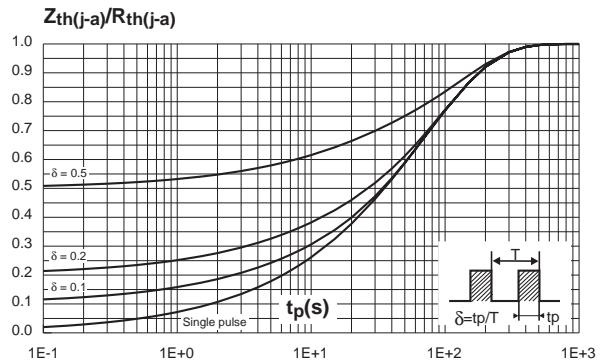


Fig. 6-1: Relative variation of thermal impedance junction to ambient versus pulse duration (DO-201AD, SMB).



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Fig. 6-2: Relative variation of thermal impedance junction to ambient versus pulse duration (DO-15).

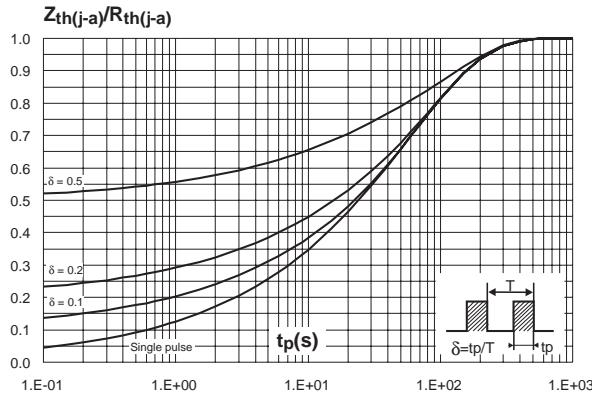


Fig. 8: Junction capacitance versus reverse voltage applied (typical values).

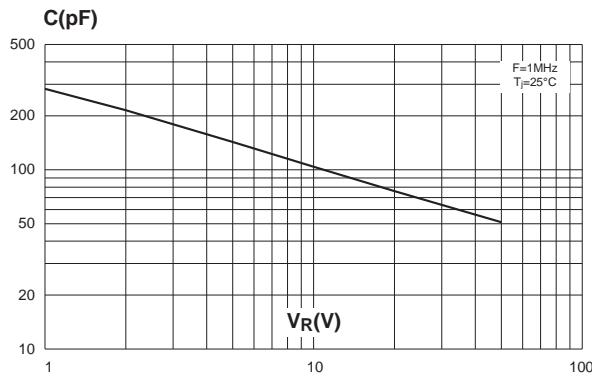


Fig. 9-2: Forward voltage drop versus forward current (low level, maximum values).

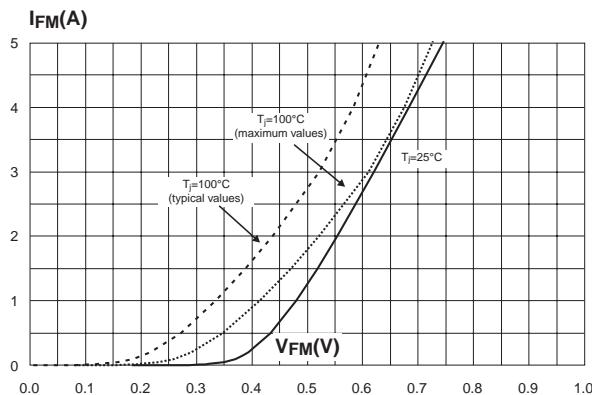


Fig. 7: Reverse leakage current versus reverse voltage applied (typical values).

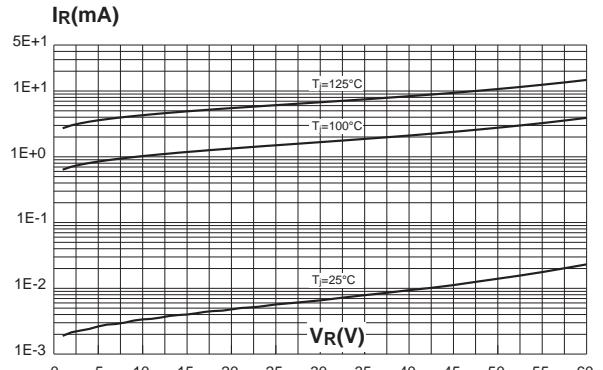


Fig. 9-1: Forward voltage drop versus forward current (high level, maximum values).

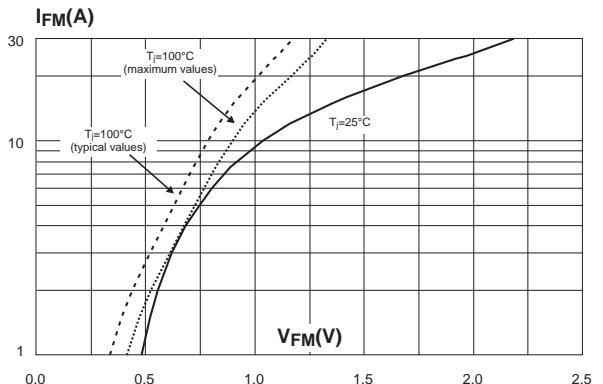
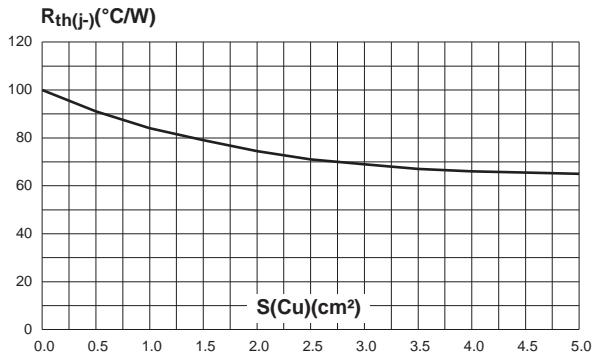
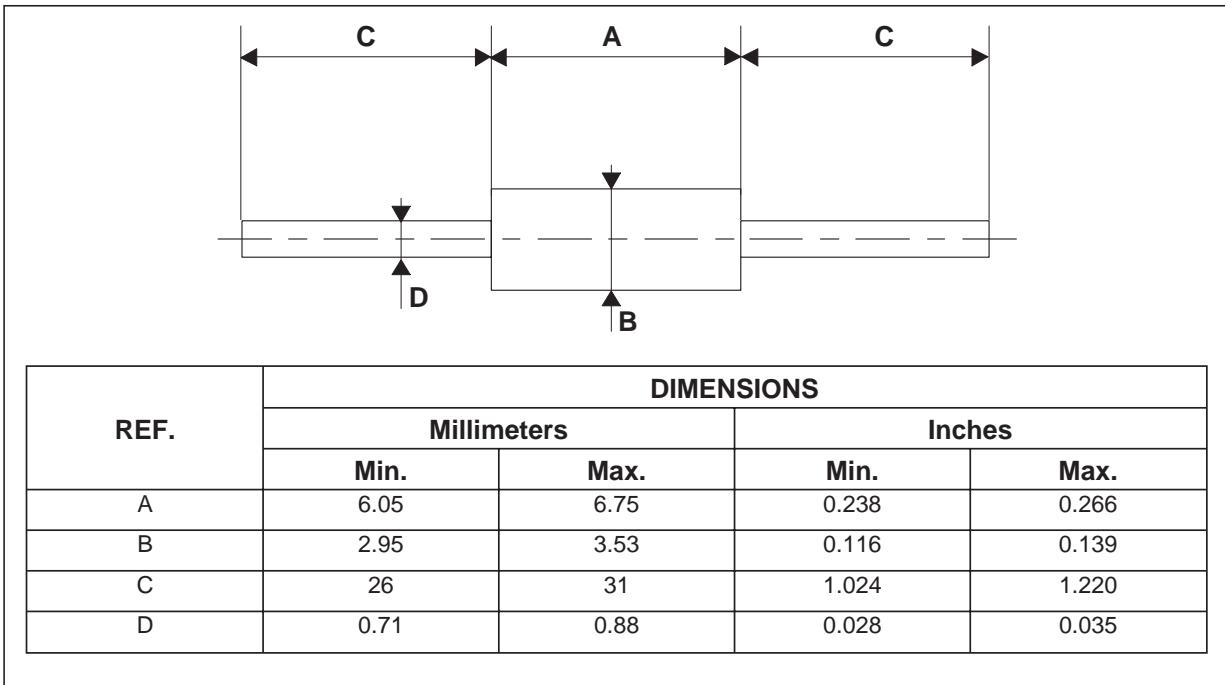


Fig. 10: Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, Cu: 35µm) (SMB).



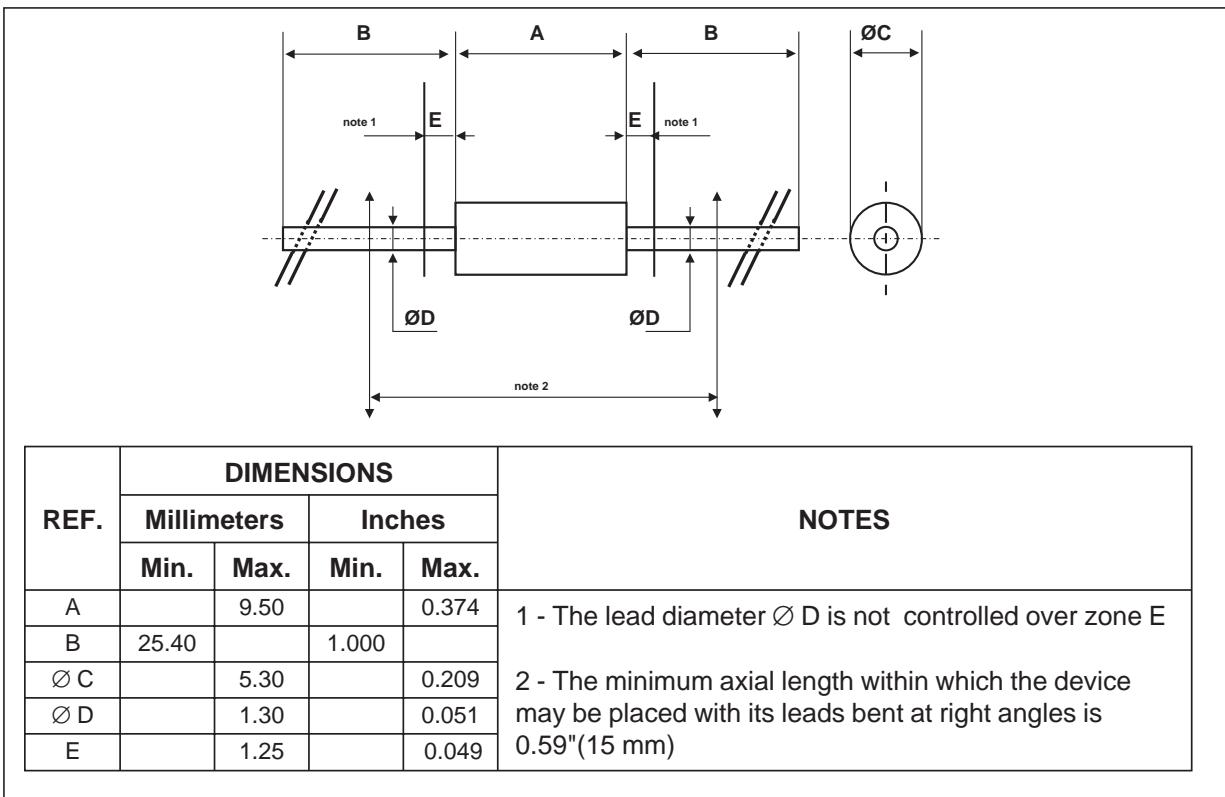
PACKAGE MECHANICAL DATA
DO-15 plastic



The diagram shows a top-down view of the DO-15 package. Dimension A is the width of the lead frame, C is the total width including the leads, B is the thickness of the lead frame, and D is the height of the lead frame. A dashed line indicates the center of the package.

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	6.05	6.75	0.238	0.266
B	2.95	3.53	0.116	0.139
C	26	31	1.024	1.220
D	0.71	0.88	0.028	0.035

PACKAGE MECHANICAL DATA
DO-201AD plastic

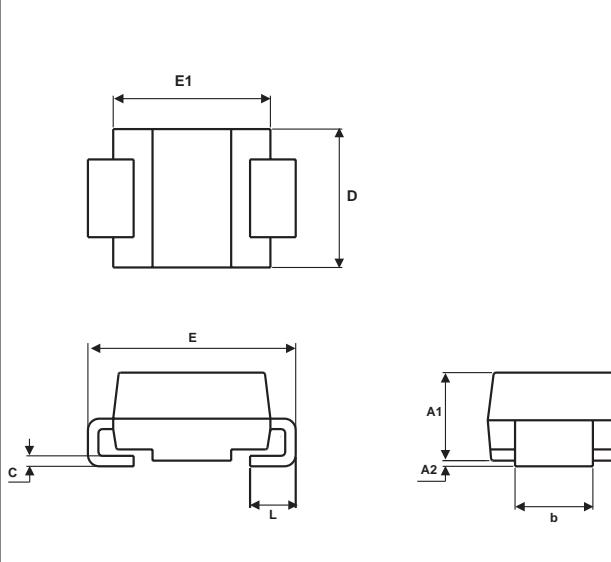


The diagram shows a top-down view of the DO-201AD package. Dimension A is the width of the lead frame, B is the total width including the leads, C is the lead diameter, D is the lead thickness, and E is the lead pitch. Note 1 specifies a lead diameter of Ø D and a lead pitch of E. Note 2 specifies a minimum axial length of 0.59" (15 mm) for bending the leads at right angles. A dashed line indicates the center of the package.

REF.	DIMENSIONS				NOTES	
	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
A		9.50		0.374	1 - The lead diameter Ø D is not controlled over zone E	
B	25.40		1.000		2 - The minimum axial length within which the device may be placed with its leads bent at right angles is 0.59"(15 mm)	
Ø C		5.30		0.209		
Ø D		1.30		0.051		
E		1.25		0.049		

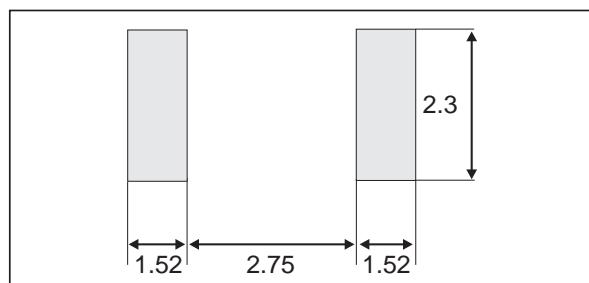
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PACKAGE MECHANICAL DATA SMB (JEDEC DO-214AA)



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.096
A2	0.05	0.20	0.002	0.008
b	1.95	2.20	0.077	0.087
c	0.15	0.41	0.006	0.016
E	5.10	5.60	0.201	0.220
E1	4.05	4.60	0.159	0.181
D	3.30	3.95	0.130	0.156
L	0.75	1.60	0.030	0.063

FOOT PRINT DIMENSIONS (in millimeters)



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS3L60	STPS3L60	DO-201AD	1.12g	600	Ammopack
STPS3L60RL	STPS3L60	DO-201AD	1.12g	1900	Tape & Reel
STPS3L60Q	STPS3L60	DO-15	0.4 g	1000	Ammopack
STPS3L60QRL	STPS3L60	DO-15	0.4 g	6000	Tape & Reel
STPS3L60U	G36	SMB	0.107 g	2500	Tape & Reel

- White band indicates cathode
- Epoxy meets UL94,V0

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